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Understanding **Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	285
Number of Logic Elements/Cells	2280
Total RAM Bits	28262
Number of I/O	101
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	132-LFBGA, CSPBGA
Supplier Device Package	132-CSPBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo2280e-4mn132i

sysCLOCK Phase Locked Loops (PLLs)

The MachXO1200 and MachXO2280 provide PLL support. The source of the PLL input divider can come from an external pin or from internal routing. There are four sources of feedback signals to the feedback divider: from CLKINTFB (internal feedback port), from the global clock nets, from the output of the post scalar divider, and from the routing (or from an external pin). There is a PLL_LOCK signal to indicate that the PLL has locked on to the input clock signal. Figure 2-10 shows the sysCLOCK PLL diagram.

The setup and hold times of the device can be improved by programming a delay in the feedback or input path of the PLL which will advance or delay the output clock with reference to the input clock. This delay can be either programmed during configuration or can be adjusted dynamically. In dynamic mode, the PLL may lose lock after adjustment and not relock until the t_{LOCK} parameter has been satisfied. Additionally, the phase and duty cycle block allows the user to adjust the phase and duty cycle of the CLKOS output.

The sysCLOCK PLLs provide the ability to synthesize clock frequencies. Each PLL has four dividers associated with it: input clock divider, feedback divider, post scalar divider, and secondary clock divider. The input clock divider is used to divide the input clock signal, while the feedback divider is used to multiply the input clock signal. The post scalar divider allows the VCO to operate at higher frequencies than the clock output, thereby increasing the frequency range. The secondary divider is used to derive lower frequency outputs.

Figure 2-10. PLL Diagram

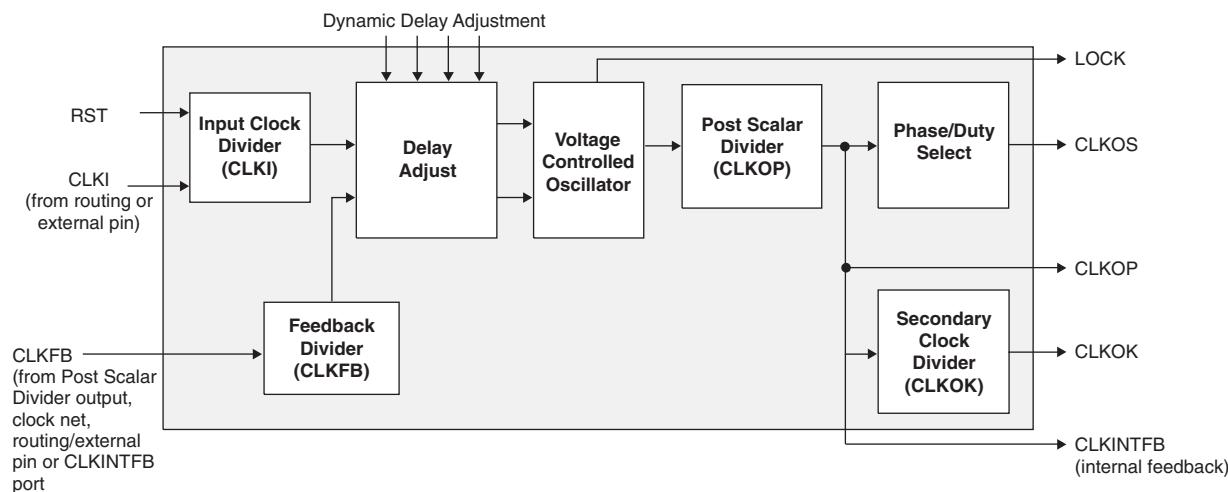
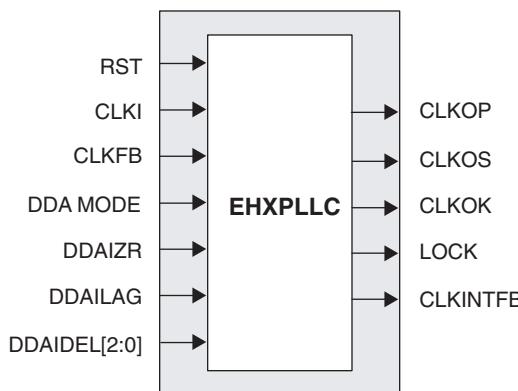


Figure 2-11 shows the available macros for the PLL. Table 2-5 provides signal description of the PLL Block.

Figure 2-11. PLL Primitive



Bus Size Matching

All of the multi-port memory modes support different widths on each of the ports. The RAM bits are mapped LSB word 0 to MSB word 0, LSB word 1 to MSB word 1 and so on. Although the word size and number of words for each port varies, this mapping scheme applies to each port.

RAM Initialization and ROM Operation

If desired, the contents of the RAM can be pre-loaded during device configuration. By preloading the RAM block during the chip configuration cycle and disabling the write controls, the sysMEM block can also be utilized as a ROM.

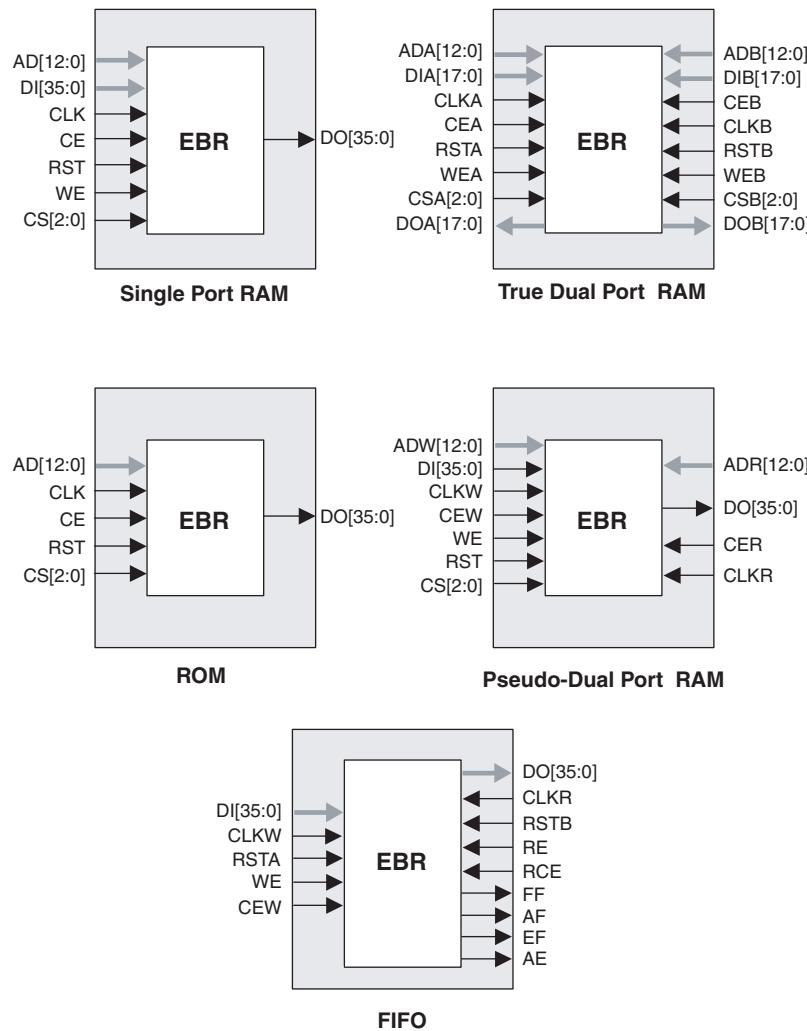
Memory Cascading

Larger and deeper blocks of RAMs can be created using EBR sysMEM Blocks. Typically, the Lattice design tools cascade memory transparently, based on specific design inputs.

Single, Dual, Pseudo-Dual Port and FIFO Modes

Figure 2-12 shows the five basic memory configurations and their input/output names. In all the sysMEM RAM modes, the input data and address for the ports are registered at the input of the memory array. The output data of the memory is optionally registered at the memory array output.

Figure 2-12. sysMEM Memory Primitives



the system. These capabilities make the MachXO ideal for many multiple power supply and hot-swap applications.

Sleep Mode

The MachXO "C" devices ($V_{CC} = 1.8/2.5/3.3V$) have a sleep mode that allows standby current to be reduced dramatically during periods of system inactivity. Entry and exit to Sleep mode is controlled by the SLEEPN pin.

During Sleep mode, the logic is non-operational, registers and EBR contents are not maintained, and I/Os are tri-stated. Do not enter Sleep mode during device programming or configuration operation. In Sleep mode, power supplies are in their normal operating range, eliminating the need for external switching of power supplies. Table 2-11 compares the characteristics of Normal, Off and Sleep modes.

Table 2-11. Characteristics of Normal, Off and Sleep Modes

Characteristic	Normal	Off	Sleep
SLEEPN Pin	High	—	Low
Static I_{CC}	Typical <10mA	0	Typical <100uA
I/O Leakage	<10 μ A	<1mA	<10 μ A
Power Supplies VCC/VCCIO/VCCAUX	Normal Range	0	Normal Range
Logic Operation	User Defined	Non Operational	Non operational
I/O Operation	User Defined	Tri-state	Tri-state
JTAG and Programming circuitry	Operational	Non-operational	Non-operational
EBR Contents and Registers	Maintained	Non-maintained	Non-maintained

SLEEPN Pin Characteristics

The SLEEPN pin behaves as an LVCMOS input with the voltage standard appropriate to the VCC supply for the device. This pin also has a weak pull-up, along with a Schmidt trigger and glitch filter to prevent false triggering. An external pull-up to VCC is recommended when Sleep Mode is not used to ensure the device stays in normal operation mode. Typically, the device enters sleep mode several hundred nanoseconds after SLEEPN is held at a valid low and restarts normal operation as specified in the Sleep Mode Timing table. The AC and DC specifications portion of this data sheet shows a detailed timing diagram.

Oscillator

Every MachXO device has an internal CMOS oscillator. The oscillator can be routed as an input clock to the clock tree or to general routing resources. The oscillator frequency can be divided by internal logic. There is a dedicated programming bit to enable/disable the oscillator. The oscillator frequency ranges from 18MHz to 26MHz.

Configuration and Testing

The following section describes the configuration and testing features of the MachXO family of devices.

IEEE 1149.1-Compliant Boundary Scan Testability

All MachXO devices have boundary scan cells that are accessed through an IEEE 1149.1 compliant test access port (TAP). This allows functional testing of the circuit board, on which the device is mounted, through a serial scan path that can access all critical logic nodes. Internal registers are linked internally, allowing test data to be shifted in and loaded directly onto test nodes, or test data to be captured and shifted out for verification. The test access port consists of dedicated I/Os: TDI, TDO, TCK and TMS. The test access port shares its power supply with one of the VCCIO Banks (MachXO256: V_{CCIO1} ; MachXO640: V_{CCIO2} ; MachXO1200 and MachXO2280: V_{CCIO5}) and can operate with LVCMOS3.3, 2.5, 1.8, 1.5, and 1.2 standards.

For more details on boundary scan test, please see information regarding additional technical documentation at the end of this data sheet.

MachXO256 and MachXO640 Hot Socketing Specifications^{1, 2, 3}

Symbol	Parameter	Condition	Min.	Typ.	Max	Units
I_{DK}	Input or I/O leakage Current	$0 \leq V_{IN} \leq V_{IH}$ (MAX)	—	—	+/-1000	μA

1. Insensitive to sequence of V_{CC} , V_{CCAUX} , and V_{CCIO} . However, assumes monotonic rise/fall rates for V_{CC} , V_{CCAUX} , and V_{CCIO} .

2. $0 \leq V_{CC} \leq V_{CC}$ (MAX), $0 \leq V_{CCIO} \leq V_{CCIO}$ (MAX) and $0 \leq V_{CCAUX} \leq V_{CCAUX}$ (MAX).

3. I_{DK} is additive to I_{PU} , I_{PD} or I_{BH} .

MachXO1200 and MachXO2280 Hot Socketing Specifications^{1, 2, 3}

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
Non-LVDS General Purpose sysIos						
I_{DK}	Input or I/O Leakage Current	$0 \leq V_{IN} \leq V_{IH}$ (MAX.)	—	—	+/-1000	μA
LVDS General Purpose sysIos						
I_{DK_LVDS}	Input or I/O Leakage Current	$V_{IN} \leq V_{CCIO}$	—	—	+/-1000	μA
		$V_{IN} > V_{CCIO}$	—	35	—	mA

1. Insensitive to sequence of V_{CC} , V_{CCAUX} , and V_{CCIO} . However, assumes monotonic rise/fall rates for V_{CC} , V_{CCAUX} , and V_{CCIO} .

2. $0 \leq V_{CC} \leq V_{CC}$ (MAX), $0 \leq V_{CCIO} \leq V_{CCIO}$ (MAX), and $0 \leq V_{CCAUX} \leq V_{CCAUX}$ (MAX).

3. I_{DK} is additive to I_{PU} , I_{PW} or I_{BH} .

DC Electrical Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{IL}, I_{IH} ^{1, 4, 5}	Input or I/O Leakage	$0 \leq V_{IN} \leq (V_{CCIO} - 0.2V)$	—	—	10	μA
		$(V_{CCIO} - 0.2V) < V_{IN} \leq 3.6V$	—	—	40	μA
I_{PU}	I/O Active Pull-up Current	$0 \leq V_{IN} \leq 0.7 V_{CCIO}$	-30	—	-150	μA
I_{PD}	I/O Active Pull-down Current	V_{IL} (MAX) $\leq V_{IN} \leq V_{IH}$ (MAX)	30	—	150	μA
$I_{B HLS}$	Bus Hold Low sustaining current	$V_{IN} = V_{IL}$ (MAX)	30	—	—	μA
$I_{B HHS}$	Bus Hold High sustaining current	$V_{IN} = 0.7V_{CCIO}$	-30	—	—	μA
$I_{B HLO}$	Bus Hold Low Overdrive current	$0 \leq V_{IN} \leq V_{IH}$ (MAX)	—	—	150	μA
$I_{B HHO}$	Bus Hold High Overdrive current	$0 \leq V_{IN} \leq V_{IH}$ (MAX)	—	—	-150	μA
V_{BHT} ³	Bus Hold trip Points	$0 \leq V_{IN} \leq V_{IH}$ (MAX)	V_{IL} (MAX)	—	V_{IH} (MIN)	V
C1	I/O Capacitance ²	$V_{CCIO} = 3.3V, 2.5V, 1.8V, 1.5V, 1.2V$, $V_{CC} = \text{Typ.}$, $V_{IO} = 0$ to V_{IH} (MAX)	—	8	—	pf
C2	Dedicated Input Capacitance ²	$V_{CCIO} = 3.3V, 2.5V, 1.8V, 1.5V, 1.2V$, $V_{CC} = \text{Typ.}$, $V_{IO} = 0$ to V_{IH} (MAX)	—	8	—	pf

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tri-stated. It is not measured with the output driver active. Bus maintenance circuits are disabled.

2. T_A 25°C, $f = 1.0MHz$

3. Please refer to V_{IL} and V_{IH} in the sysIO Single-Ended DC Electrical Characteristics table of this document.

4. Not applicable to SLEEPN pin.

5. When V_{IH} is higher than V_{CCIO} , a transient current typically of 30ns in duration or less with a peak current of 6mA can occur on the high-to-low transition. For MachXO1200 and MachXO2280 true LVDS output pins, V_{IH} must be less than or equal to V_{CCIO} .

Supply Current (Sleep Mode)^{1,2}

Symbol	Parameter	Device	Typ. ³	Max.	Units
I_{CC}	Core Power Supply	LCMxo256C	12	25	μA
		LCMxo640C	12	25	μA
		LCMxo1200C	12	25	μA
		LCMxo2280C	12	25	μA
I_{CCAUX}	Auxiliary Power Supply	LCMxo256C	1	15	μA
		LCMxo640C	1	25	μA
		LCMxo1200C	1	45	μA
		LCMxo2280C	1	85	μA
I_{CCIO}	Bank Power Supply ⁴	All LCMxo 'C' Devices	2	30	μA

1. Assumes all inputs are configured as LVCMOS and held at the VCCIO or GND.

2. Frequency = 0MHz.

3. $T_A = 25^\circ C$, power supplies at nominal voltage.

4. Per Bank.

Supply Current (Standby)^{1, 2, 3, 4}

Over Recommended Operating Conditions

Symbol	Parameter	Device	Typ. ⁵	Units
I_{CC}	Core Power Supply	LCMxo256C	7	mA
		LCMxo640C	9	mA
		LCMxo1200C	14	mA
		LCMxo2280C	20	mA
		LCMxo256E	4	mA
		LCMxo640E	6	mA
		LCMxo1200E	10	mA
		LCMxo2280E	12	mA
I_{CCAUX}	Auxiliary Power Supply $V_{CCAUX} = 3.3V$	LCMxo256E/C	5	mA
		LCMxo640E/C	7	mA
		LCMxo1200E/C	12	mA
		LCMxo2280E/C	13	mA
I_{CCIO}	Bank Power Supply ⁶	All devices	2	mA

1. For further information on supply current, please see details of additional technical documentation at the end of this data sheet.

2. Assumes all outputs are tristated, all inputs are configured as LVCMOS and held at V_{CCIO} or GND.

3. Frequency = 0MHz.

4. User pattern = blank.

5. $T_J = 25^\circ C$, power supplies at nominal voltage.

6. Per Bank. $V_{CCIO} = 2.5V$. Does not include pull-up/pull-down.

Initialization Supply Current^{1, 2, 3, 4}

Over Recommended Operating Conditions

Symbol	Parameter	Device	Typ. ⁵	Units
I _{CC}	Core Power Supply	LCMxo256C	13	mA
		LCMxo640C	17	mA
		LCMxo1200C	21	mA
		LCMxo2280C	23	mA
		LCMxo256E	10	mA
		LCMxo640E	14	mA
		LCMxo1200E	18	mA
		LCMxo2280E	20	mA
I _{CCAUX}	Auxiliary Power Supply V _{CCAUX} = 3.3V	LCMxo256C/E	10	mA
		LCMxo640E/C	13	mA
		LCMxo1200E/C	24	mA
		LCMxo2280E/C	25	mA
I _{CCIO}	Bank Power Supply ⁶	All devices	2	mA

1. For further information on supply current, please see details of additional technical documentation at the end of this data sheet.
2. Assumes all I/O pins are held at V_{CCIO} or GND.
3. Frequency = 0MHz.
4. Typical user pattern.
5. T_J = 25°C, power supplies at nominal voltage.
6. Per Bank, V_{CCIO} = 2.5V. Does not include pull-up/pull-down.

Programming and Erase Flash Supply Current^{1, 2, 3, 4}

Symbol	Parameter	Device	Typ. ⁵	Units
I _{CC}	Core Power Supply	LCMxo256C	9	mA
		LCMxo640C	11	mA
		LCMxo1200C	16	mA
		LCMxo2280C	22	mA
		LCMxo256E	6	mA
		LCMxo640E	8	mA
		LCMxo1200E	12	mA
		LCMxo2280E	14	mA
I _{CCAUX}	Auxiliary Power Supply V _{CCAUX} = 3.3V	LCMxo256C/E	8	mA
		LCMxo640C/E	10	mA
		LCMxo1200/E	15	mA
		LCMxo2280C/E	16	mA
I _{CCIO}	Bank Power Supply ⁶	All devices	2	mA

1. For further information on supply current, please see details of additional technical documentation at the end of this data sheet.
2. Assumes all I/O pins are held at V_{CCIO} or GND.
3. Typical user pattern.
4. JTAG programming is at 25MHz.
5. T_J = 25°C, power supplies at nominal voltage.
6. Per Bank. V_{CCIO} = 2.5V. Does not include pull-up/pull-down.

sysIO Differential Electrical Characteristics

LVDS

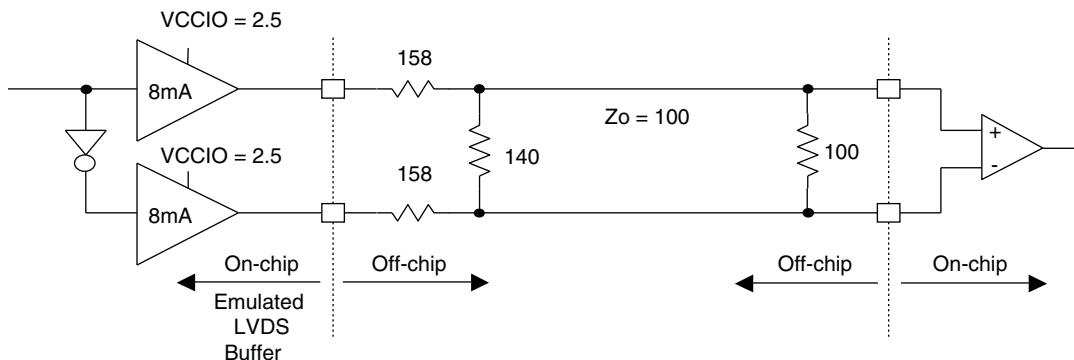
Over Recommended Operating Conditions

Parameter Symbol	Parameter Description	Test Conditions	Min.	Typ.	Max.	Units
V_{INP}, V_{INM}	Input Voltage		0	—	2.4	V
V_{THD}	Differential Input Threshold		+/-100	—	—	mV
V_{CM}	Input Common Mode Voltage	$100\text{mV} \leq V_{THD}$	$V_{THD}/2$	1.2	1.8	V
		$200\text{mV} \leq V_{THD}$	$V_{THD}/2$	1.2	1.9	V
		$350\text{mV} \leq V_{THD}$	$V_{THD}/2$	1.2	2.0	V
I_{IN}	Input current	Power on	—	—	+/-10	μA
V_{OH}	Output high voltage for V_{OP} or V_{OM}	$R_T = 100 \text{ Ohm}$	—	1.38	1.60	V
V_{OL}	Output low voltage for V_{OP} or V_{OM}	$R_T = 100 \text{ Ohm}$	0.9V	1.03	—	V
V_{OD}	Output voltage differential	$(V_{OP} - V_{OM}), R_T = 100 \text{ Ohm}$	250	350	450	mV
ΔV_{OD}	Change in V_{OD} between high and low		—	—	50	mV
V_{OS}	Output voltage offset	$(V_{OP} - V_{OM})/2, R_T = 100 \text{ Ohm}$	1.125	1.25	1.375	V
ΔV_{OS}	Change in V_{OS} between H and L		—	—	50	mV
I_{OSD}	Output short circuit current	$V_{OD} = 0\text{V}$ Driver outputs shorted	—	—	6	mA

LVDS Emulation

MachXO devices can support LVDS outputs via emulation (LVDS25E), in addition to the LVDS support that is available on-chip on certain devices. The output is emulated using complementary LVCMS outputs in conjunction with resistors across the driver outputs on all devices. The scheme shown in Figure 3-1 is one possible solution for LVDS standard implementation. Resistor values in Figure 3-1 are industry standard values for 1% resistors.

Figure 3-1. LVDS Using External Resistors (LVDS25E)



Note: All resistors are $\pm 1\%$.

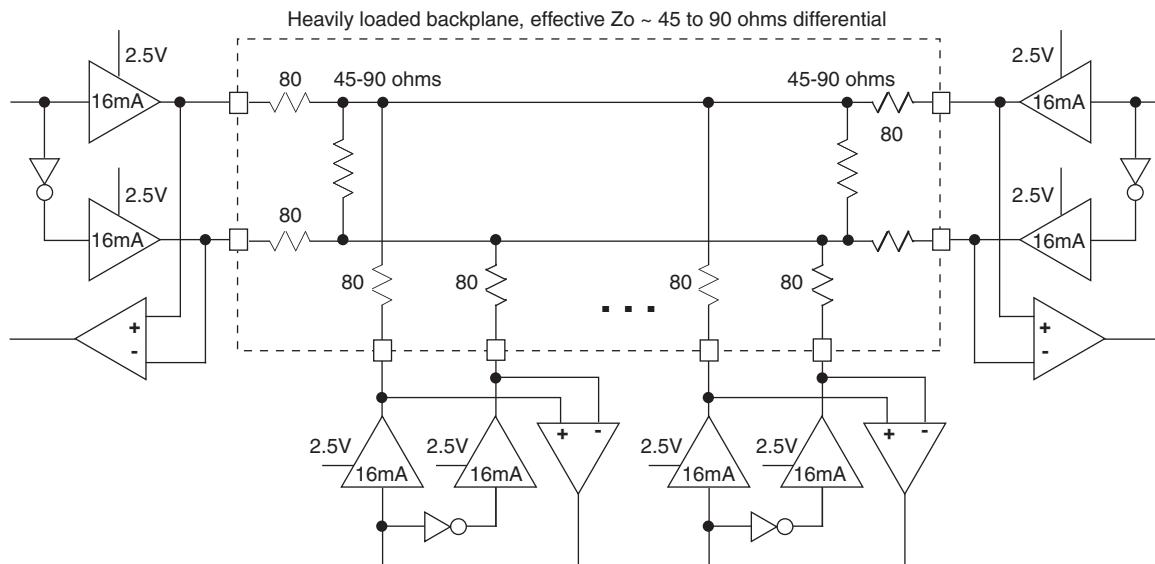
The LVDS differential input buffers are available on certain devices in the MachXO family.

Table 3-1. LVDS DC Conditions
Over Recommended Operating Conditions

Parameter	Description	Typical	Units
Z_{OUT}	Output impedance	20	Ω
R_S	Driver series resistor	294	Ω
R_P	Driver parallel resistor	121	Ω
R_T	Receiver termination	100	Ω
V_{OH}	Output high voltage	1.43	V
V_{OL}	Output low voltage	1.07	V
V_{OD}	Output differential voltage	0.35	V
V_{CM}	Output common mode voltage	1.25	V
Z_{BACK}	Back impedance	100	Ω
I_{DC}	DC output current	3.66	mA

BLVDS

The MachXO family supports the BLVDS standard through emulation. The output is emulated using complementary LVCMS outputs in conjunction with a parallel external resistor across the driver outputs. The input standard is supported by the LVDS differential input buffer on certain devices. BLVDS is intended for use when multi-drop and bi-directional multi-point differential signaling is required. The scheme shown in Figure 3-2 is one possible solution for bi-directional multi-point differential signals.

Figure 3-2. BLVDS Multi-point Output Example


MachXO Family Timing Adders^{1, 2, 3}

Over Recommended Operating Conditions

Buffer Type	Description	-5	-4	-3	Units
Input Adjusters					
LVDS25 ⁴	LVDS	0.44	0.53	0.61	ns
BLVDS25 ⁴	BLVDS	0.44	0.53	0.61	ns
LVPECL33 ⁴	LVPECL	0.42	0.50	0.59	ns
LVTTL33	LVTTL	0.01	0.01	0.01	ns
LVCMOS33	LVCMOS 3.3	0.01	0.01	0.01	ns
LVCMOS25	LVCMOS 2.5	0.00	0.00	0.00	ns
LVCMOS18	LVCMOS 1.8	0.07	0.08	0.10	ns
LVCMOS15	LVCMOS 1.5	0.14	0.17	0.19	ns
LVCMOS12	LVCMOS 1.2	0.40	0.48	0.56	ns
PCI33 ⁴	PCI	0.01	0.01	0.01	ns
Output Adjusters					
LVDS25E	LVDS 2.5 E	-0.13	-0.15	-0.18	ns
LVDS25 ⁴	LVDS 2.5	-0.21	-0.26	-0.30	ns
BLVDS25	BLVDS 2.5	-0.03	-0.03	-0.04	ns
LVPECL33	LVPECL 3.3	0.04	0.04	0.05	ns
LVTTL33_4mA	LVTTL 4mA drive	0.04	0.04	0.05	ns
LVTTL33_8mA	LVTTL 8mA drive	0.06	0.07	0.08	ns
LVTTL33_12mA	LVTTL 12mA drive	-0.01	-0.01	-0.01	ns
LVTTL33_16mA	LVTTL 16mA drive	0.50	0.60	0.70	ns
LVCMOS33_4mA	LVCMOS 3.3 4mA drive	0.04	0.04	0.05	ns
LVCMOS33_8mA	LVCMOS 3.3 8mA drive	0.06	0.07	0.08	ns
LVCMOS33_12mA	LVCMOS 3.3 12mA drive	-0.01	-0.01	-0.01	ns
LVCMOS33_14mA	LVCMOS 3.3 14mA drive	0.50	0.60	0.70	ns
LVCMOS25_4mA	LVCMOS 2.5 4mA drive	0.05	0.06	0.07	ns
LVCMOS25_8mA	LVCMOS 2.5 8mA drive	0.10	0.12	0.13	ns
LVCMOS25_12mA	LVCMOS 2.5 12mA drive	0.00	0.00	0.00	ns
LVCMOS25_14mA	LVCMOS 2.5 14mA drive	0.34	0.40	0.47	ns
LVCMOS18_4mA	LVCMOS 1.8 4mA drive	0.11	0.13	0.15	ns
LVCMOS18_8mA	LVCMOS 1.8 8mA drive	0.05	0.06	0.06	ns
LVCMOS18_12mA	LVCMOS 1.8 12mA drive	-0.06	-0.07	-0.08	ns
LVCMOS18_14mA	LVCMOS 1.8 14mA drive	0.06	0.07	0.09	ns
LVCMOS15_4mA	LVCMOS 1.5 4mA drive	0.15	0.19	0.22	ns
LVCMOS15_8mA	LVCMOS 1.5 8mA drive	0.05	0.06	0.07	ns
LVCMOS12_2mA	LVCMOS 1.2 2mA drive	0.26	0.31	0.36	ns
LVCMOS12_6mA	LVCMOS 1.2 6mA drive	0.05	0.06	0.07	ns
PCI33 ⁴	PCI33	1.85	2.22	2.59	ns

1. Timing adders are characterized but not tested on every device.
2. LVCMOS timing is measured with the load specified in Switching Test Conditions table.
3. All other standards tested according to the appropriate specifications.
4. I/O standard only available in LCMXO1200 and LCMXO2280 devices.

Rev. A 0.19

sysCLOCK PLL Timing

Over Recommended Operating Conditions

Parameter	Descriptions	Conditions	Min.	Max.	Units
f_{IN}	Input Clock Frequency (CLKI, CLKFB)		25	420	MHz
		Input Divider (M) = 1; Feedback Divider (N) <= 4 ^{5, 6}	18	25	MHz
f_{OUT}	Output Clock Frequency (CLKOP, CLKOS)		25	420	MHz
f_{OUT2}	K-Divider Output Frequency (CLKOK)		0.195	210	MHz
f_{VCO}	PLL VCO Frequency		420	840	MHz
f_{PFD}	Phase Detector Input Frequency		25	—	MHz
		Input Divider (M) = 1; Feedback Divider (N) <= 4 ^{5, 6}	18	25	MHz
AC Characteristics					
t_{DT}	Output Clock Duty Cycle	Default duty cycle selected ³	45	55	%
t_{PH}^4	Output Phase Accuracy		—	0.05	UI
t_{OPJIT}^1	Output Clock Period Jitter	$f_{OUT} \geq 100$ MHz	—	+/-120	ps
		$f_{OUT} < 100$ MHz	—	0.02	UIPP
t_{SK}	Input Clock to Output Clock Skew	Divider ratio = integer	—	+/-200	ps
t_W	Output Clock Pulse Width	At 90% or 10% ³	1	—	ns
t_{LOCK}^2	PLL Lock-in Time		—	150	μs
t_{PA}	Programmable Delay Unit		100	450	ps
t_{IPJIT}	Input Clock Period Jitter	$f_{OUT} \geq 100$ MHz	—	+/-200	ps
		$f_{OUT} < 100$ MHz	—	0.02	UI
t_{FBKDLY}	External Feedback Delay		—	10	ns
t_{HI}	Input Clock High Time	90% to 90%	0.5	—	ns
t_{LO}	Input Clock Low Time	10% to 10%	0.5	—	ns
t_{RST}	RST Pulse Width		10	—	ns

1. Jitter sample is taken over 10,000 samples of the primary PLL output with a clean reference clock.

2. Output clock is valid after t_{LOCK} for PLL reset and dynamic delay adjustment.

3. Using LVDS output buffers.

4. CLKOS as compared to CLKOP output.

5. When using an input frequency less than 25 MHz the output frequency must be less than or equal to 4 times the input frequency.

6. The on-chip oscillator can be used to provide reference clock input to the PLL provided the output frequency restriction for clock inputs below 25 MHz are followed.

Rev. A 0.19

Power Supply and NC (Cont.)

Signal	132 csBGA ¹	256 caBGA / 256 ftBGA ¹	324 ftBGA ¹
VCC	H3, P6, G12, C7	G7, G10, K7, K10	F14, G11, G9, H7, L7, M9
VCCIO0	LCMxo640: B11, C5 LCMxo1200/2280: C5	LCMxo640: F8, F7, F9, F10 LCMxo1200/2280: F8, F7	G8, G7
VCCIO1	LCMxo640: L12, E12 LCMxo1200/2280: B11	LCMxo640: H11, G11, K11, J11 LCMxo1200/2280: F9, F10	G12, G10
VCCIO2	LCMxo640: N2, M10 LCMxo1200/2280: E12	LCMxo640: L9, L10, L8, L7 LCMxo1200/2280: H11, G11	J12, H12
VCCIO3	LCMxo640: D2, K3 LCMxo1200/2280: L12	LCMxo640: K6, J6, H6, G6 LCMxo1200/2280: K11, J11	L12, K12
VCCIO4	LCMxo640: None LCMxo1200/2280: M10	LCMxo640: None LCMxo1200/2280: L9, L10	M12, M11
VCCIO5	LCMxo640: None LCMxo1200/2280: N2	LCMxo640: None LCMxo1200/2280: L8, L7	M8, R9
VCCIO6	LCMxo640: None LCMxo1200/2280: K3	LCMxo640: None LCMxo1200/2280: K6, J6	M7, K7
VCCIO7	LCMxo640: None LCMxo1200/2280: D2	LCMxo640: None LCMxo1200/2280: H6, G6	H6, J7
VCCAUX	P7, A7	T9, A8	M10, F9
GND ²	F1, P9, J14, C9, A10, B4, L13, D13, P2, N11, E1, L2	A1, A16, F11, G8, G9, H7, H8, H9, H10, J7, J8, J9, J10, K8, K9, L6, T1, T16	E14, F16, H10, H11, H8, H9, J10, J11, J4, J8, J9, K10, K11, K17, K8, K9, L10, L11, L8, L9, N2, P14, P5, R7
NC ³	—	LCMxo640: E4, E5, F5, F6, C3, C2, G4, G5, H4, H5, K5, K4, M5, M4, P2, P3, N5, N6, M7, M8, N10, N11, R15, R16, P15, P16, M11, L11, N12, N13, M13, M12, K12, J12, F12, F13, E12, E13, D13, D14, B15, A15, C14, B14, E11, E10, E7, E6, D4, D3, B3, B2 LCMxo1200: None LCMxo2280: None	—

1. Pin orientation A1 starts from the upper left corner of the top side view with alphabetical order ascending vertically and numerical order ascending horizontally.
2. All grounds must be electrically connected at the board level. For fpBGA and ftBGA packages, the total number of GND balls is less than the actual number of GND logic connections from the die to the common package GND plane.
3. NC pins should not be connected to any active signals, VCC or GND.

**LCMxo640, LCMxo1200 and LCMxo2280 Logic Signal Connections:
 144 TQFP (Cont.)**

Pin Number	LCMxo640				LCMxo1200				LCMxo2280			
	Ball Function	Bank	Dual Function	Differential	Ball Function	Bank	Dual Function	Differential	Ball Function	Bank	Dual Function	Differential
51	TDI	2	TDI		TDI	5	TDI		TDI	5	TDI	
52	VCC	-			VCC	-			VCC	-		
53	VCCAUX	-			VCCAUX	-			VCCAUX	-		
54	PB5A	2		T	PB6F	5			PB8F	5		
55	PB5B	2	PCLKT2_1***	C	PB7B	4	PCLK4_1***		PB10F	4	PCLK4_1***	
56	PB5D	2			PB7C	4			PB10C	4		T
57	PB6A	2		T	PB7D	4			PB10D	4		C
58	PB6B	2	PCLKT2_0***	C	PB7F	4	PCLK4_0***		PB10B	4	PCLK4_0***	
59	GND	-			GND	-			GND	-		
60	PB7C	2			PB9A	4			PB12A	4		T
61	PB7E	2			PB9B	4			PB12B	4		C
62	PB8A	2			PB9E	4			PB12E	4		
63	VCCIO2	2			VCCIO4	4			VCCIO4	4		
64	GNDIO2	2			GNDIO4	4			GNDIO4	4		
65	PB8C	2		T	PB10A	4			PB13A	4		T
66	PB8D	2		C	PB10B	4			PB13B	4		C
67	PB9A	2		T	PB10C	4			PB13C	4		T
68	PB9C	2		T	PB10D	4			PB13D	4		C
69	PB9B	2		C	PB10F	4			PB14D	4		
70**	SLEEPN	-	SLEEPN		SLEEPN	-	SLEEPN		SLEEPN	-	SLEEPN	
71	PB9D	2		C	PB11C	4			PB16C	4		T
72	PB9F	2			PB11D	4			PB16D	4		C
73	PR11D	1		C	PR16B	3			PR20B	3		C
74	PR11B	1		C	PR16A	3			PR20A	3		T
75	PR11C	1		T	PR15B	3			PR19B	3		C
76	PR10D	1		C	PR15A	3			PR19A	3		T
77	PR11A	1		T	PR14D	3			PR17D	3		C
78	PR10B	1		C	PR14C	3			PR17C	3		T
79	PR10C	1		T	PR14B	3			PR17B	3		C*
80	PR10A	1		T	PR14A	3			PR17A	3		T*
81	PR9D	1			PR13D	3			PR16D	3		
82	VCCIO1	1			VCCIO3	3			VCCIO3	3		
83	GNDIO1	1			GNDIO3	3			GNDIO3	3		
84	PR9A	1			PR12B	3			PR15B	3		C*
85	PR8C	1			PR12A	3			PR15A	3		T*
86	PR8A	1			PR11B	3			PR14B	3		C*
87	PR7D	1			PR11A	3			PR14A	3		T*
88	GND	-			GND	-			GND	-		
89	PR7B	1		C	PR10B	3			PR13B	3		C*
90	PR7A	1		T	PR10A	3			PR13A	3		T*
91	PR6D	1		C	PR8B	2			PR10B	2		C*
92	PR6C	1		T	PR8A	2			PR10A	2		T*
93	VCC	-			VCC	-			VCC	-		
94	PR5D	1			PR6B	2			PR8B	2		C*
95	PR5B	1			PR6A	2			PR8A	2		T*
96	PR4D	1			PR5B	2			PR7B	2		C*
97	PR4B	1		C	PR5A	2			PR7A	2		T*
98	VCCIO1	1			VCCIO2	2			VCCIO2	2		
99	GNDIO1	1			GNDIO2	2			GNDIO2	2		
100	PR4A	1		T	PR4C	2			PR5C	2		

**LCMxo640, LCMxo1200 and LCMxo2280 Logic Signal Connections:
 256 caBGA / 256 ftBGA (Cont.)**

LCMxo640				LCMxo1200				LCMxo2280					
Ball Number	Ball Function	Bank	Dual Function	Ball Number	Ball Function	Bank	Dual Function	Ball Number	Ball Function	Bank	Dual Function		
J4	PL8A	3	T	J4	PL13A	6	T*	J4	PL16A	6	T*		
J5	PL8B	3	C	J5	PL13B	6	C*	J5	PL16B	6	C*		
R1	PL11A	3	T	R1	PL13C	6	T	R1	PL16C	6	T		
R2	PL11B	3	C	R2	PL13D	6	C	R2	PL16D	6	C		
-	-	-	-	-	-	-	-	GND	GND	-	-		
K5	NC			K5	PL14A	6	LLM0_PLLT_FB_A	T*	K5	PL17A	6	LLM0_PLLT_FB_A	
K4	NC			K4	PL14B	6	LLM0_PLLC_FB_A	C*	K4	PL17B	6	LLM0_PLLC_FB_A	
L5	PL10C	3	T	L5	PL14C	6	T	L5	PL17C	6	T		
L4	PL10D	3	C	L4	PL14D	6	C	L4	PL17D	6	C		
M5	NC			M5	PL15A	6	LLM0_PLLT_IN_A	T*	M5	PL18A	6	LLM0_PLLT_IN_A	
M4	NC			M4	PL15B	6	LLM0_PLLC_IN_A	C*	M4	PL18B	6	LLM0_PLLC_IN_A	
N4	PL11C	3	T	N4	PL16A	6	T	N4	PL19A	6	T		
N3	PL11D	3	C	N3	PL16B	6	C	N3	PL19B	6	C		
VCCIO3	VCCIO3	3		VCCIO6	VCCIO6	6		VCCIO6	VCCIO6	6			
GND	GNDIO3	3		GND	GNDIO6	6		GND	GNDIO6	6			
GND	GNDIO2	2		GND	GNDIO5	5		GND	GNDIO5	5			
VCCIO2	VCCIO2	2		VCCIO5	VCCIO5	5		VCCIO5	VCCIO5	5			
P4	TMS	2	TMS	P4	TMS	5	TMS	P4	TMS	5	TMS		
P2	NC			P2	PB2A	5	T	P2	PB2A	5	T		
P3	NC			P3	PB2B	5	C	P3	PB2B	5	C		
N5	NC			N5	PB2C	5	T	N5	PB2C	5	T		
R3	TCK	2	TCK	R3	TCK	5	TCK	R3	TCK	5	TCK		
N6	NC			N6	PB2D	5	C	N6	PB2D	5	C		
T2	PB2A	2	T	T2	PB3A	5	T	T2	PB3A	5	T		
T3	PB2B	2	C	T3	PB3B	5	C	T3	PB3B	5	C		
R4	PB2C	2	T	R4	PB3C	5	T	R4	PB3C	5	T		
R5	PB2D	2	C	R5	PB3D	5	C	R5	PB3D	5	C		
P5	PB3A	2	T	P5	PB4A	5	T	P5	PB4A	5	T		
P6	PB3B	2	C	P6	PB4B	5	C	P6	PB4B	5	C		
T5	PB3C	2	T	T5	PB4C	5	T	T5	PB4C	5	T		
M6	TDO	2	TDO	M6	TDO	5	TDO	M6	TDO	5	TDO		
T4	PB3D	2	C	T4	PB4D	5	C	T4	PB4D	5	C		
R6	PB4A	2	T	R6	PB5A	5	T	R6	PB5A	5	T		
GND	GNDIO2	2		GND	GNDIO5	5		GND	GNDIO5	5			
VCCIO2	VCCIO2	2		VCCIO5	VCCIO5	5		VCCIO5	VCCIO5	5			
T6	PB4B	2	C	T6	PB5B	5	C	T6	PB5B	5	C		
N7	TDI	2	TDI	N7	TDI	5	TDI	N7	TDI	5	TDI		
T8	PB4C	2	T	T8	PB5C	5	T	T8	PB6A	5	T		
T7	PB4D	2	C	T7	PB5D	5	C	T7	PB6B	5	C		
M7	NC			M7	PB6A	5	T	M7	PB7C	5	T		
M8	NC			M8	PB6B	5	C	M8	PB7D	5	C		
T9	VCCAUX	-		T9	VCCAUX	-		T9	VCCAUX	-			
R7	PB4E	2	T	R7	PB6C	5	T	R7	PB8C	5	T		
R8	PB4F	2	C	R8	PB6D	5	C	R8	PB8D	5	C		
-	-			VCCIO5	VCCIO5	5		VCCIO5	VCCIO5	5			
-	-			GND	GNDIO5	5		GND	GNDIO5	5			
P7	PB5C	2	T	P7	PB6E	5	T	P7	PB9A	4	T		
P8	PB5D	2	C	P8	PB6F	5	C	P8	PB9B	4	C		
N8	PB5A	2	T	N8	PB7A	4	T	N8	PB10E	4	T		
N9	PB5B	2	PCLK2_1***	C	N9	PB7B	4	PCLK4_1***	C	N9	PB10F	4	PCLK4_1***
P10	PB7B	2	C	P10	PB7D	4	C	P10	PB10D	4	C		
P9	PB7A	2	T	P9	PB7C	4	T	P9	PB10C	4	T		
M9	PB6B	2	PCLK2_0***	C	M9	PB7F	4	PCLK4_0***	C	M9	PB10B	4	PCLK4_0***

LCMxo2280 Logic Signal Connections: 324 ftBGA (Cont.)

LCMxo2280				
Ball Number	Ball Function	Bank	Dual Function	Differential
G2	PL11A	6		T*
H2	PL11B	6		C*
L3	PL11C	6		T
L5	PL11D	6		C
H1	PL12A	6		T*
VCCIO6	VCCIO6	6		
GND	GNDIO6	6		
J2	PL12B	6		C*
L4	PL12C	6		T
L6	PL12D	6		C
K2	PL13A	6		T*
K1	PL13B	6		C*
J1	PL13C	6		T
VCC	VCC	-		
L2	PL13D	6		C
M5	PL14D	6		C
M3	PL14C	6	TSALL	T
L1	PL14B	6		C*
M2	PL14A	6		T*
M1	PL15A	6		T*
N1	PL15B	6		C*
M6	PL15C	6		T
M4	PL15D	6		C
VCCIO6	VCCIO6	6		
GND	GNDIO6	6		
P1	PL16A	6		T*
P2	PL16B	6		C*
N3	PL16C	6		T
N4	PL16D	6		C
GND	GND	-		
T1	PL17A	6	LLM0_PLLT_FB_A	T*
R1	PL17B	6	LLM0_PLLC_FB_A	C*
P3	PL17C	6		T
N5	PL17D	6		C
R3	PL18A	6	LLM0_PLLT_IN_A	T*
R2	PL18B	6	LLM0_PLLC_IN_A	C*
P4	PL19A	6		T
N6	PL19B	6		C
U1	PL20A	6		T
VCCIO6	VCCIO6	6		
GND	GNDIO6	6		
GND	GNDIO5	5		
VCCIO5	VCCIO5	5		

LCMxo2280 Logic Signal Connections: 324 ftBGA (Cont.)

LCMxo2280				
Ball Number	Ball Function	Bank	Dual Function	Differential
J13	PR10C	2		T
M18	PR10B	2		C*
L18	PR10A	2		T*
GND	GNDIO2	2		
VCCIO2	VCCIO2	2		
H16	PR9D	2		C
H14	PR9C	2		T
K18	PR9B	2		C*
J18	PR9A	2		T*
J17	PR8D	2		C
VCC	VCC	-		
H18	PR8C	2		T
H17	PR8B	2		C*
G17	PR8A	2		T*
H13	PR7D	2		C
H15	PR7C	2		T
G18	PR7B	2		C*
F18	PR7A	2		T*
G14	PR6D	2		C
G16	PR6C	2		T
VCCIO2	VCCIO2	2		
GND	GNDIO2	2		
E18	PR6B	2		C*
F17	PR6A	2		T*
G13	PR5D	2		C
G15	PR5C	2		T
E17	PR5B	2		C*
E16	PR5A	2		T*
GND	GND	-		
F15	PR4D	2		C
E15	PR4C	2		T
D17	PR4B	2		C*
D18	PR4A	2		T*
B18	PR3D	2		C
C18	PR3C	2		T
C16	PR3B	2		C*
D16	PR3A	2		T*
C17	PR2B	2		C
D15	PR2A	2		T
VCCIO2	VCCIO2	2		
GND	GNDIO2	2		
GND	GNDIO1	1		
VCCIO1	VCCIO1	1		

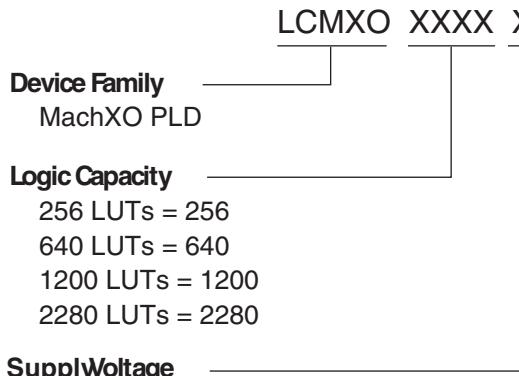


MachXO Family Data Sheet Ordering Information

June 2013

Data Sheet DS1002

Part Number Description



Note: Parts dual marked as described

ES = Engineering Sample
Blank = Production Device

Grade

C = Commercial
I = Industrial

Package

T100 = 100-pin TQFP
T144 = 144-pin TQFP
M100 = 100-ball csBGA
M132 = 132-ball csBGA
B256 = 256-ball caBGA
FT256 = 256-ball ftBGA
FT324 = 324-ball ftBGA

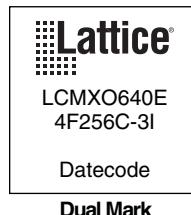
TN100 = 100-pin Lead-Free TQFP
TN144 = 144-pin Lead-Free TQFP
MN100 = 100-ball Lead-Free csBGA
MN132 = 132-ball Lead-Free csBGA
BN256 = 256-ball Lead-Free caBGA
FTN256 = 256-ball Lead-Free ftBGA
FTN324 = 324-ball Lead-Free ftBGA

Speed

3 = Slowest
4
5 = Fastest

Ordering Information

Note: MachXO devices are dual marked except the slowest commercial speed grade device. For example the commercial speed grade LCMXO640E-4F256C is also marked with industrial grade -3I grade. The slowest commercial speed grade does not have industrial markings. The markings appears as follows:



Conventional Packaging

Commercial

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo256C-3T100C	256	1.8V/2.5V/3.3V	78	-3	TQFP	100	COM
LCMxo256C-4T100C	256	1.8V/2.5V/3.3V	78	-4	TQFP	100	COM
LCMxo256C-5T100C	256	1.8V/2.5V/3.3V	78	-5	TQFP	100	COM
LCMxo256C-3M100C	256	1.8V/2.5V/3.3V	78	-3	csBGA	100	COM
LCMxo256C-4M100C	256	1.8V/2.5V/3.3V	78	-4	csBGA	100	COM
LCMxo256C-5M100C	256	1.8V/2.5V/3.3V	78	-5	csBGA	100	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo640C-3T100C	640	1.8V/2.5V/3.3V	74	-3	TQFP	100	COM
LCMxo640C-4T100C	640	1.8V/2.5V/3.3V	74	-4	TQFP	100	COM
LCMxo640C-5T100C	640	1.8V/2.5V/3.3V	74	-5	TQFP	100	COM
LCMxo640C-3M100C	640	1.8V/2.5V/3.3V	74	-3	csBGA	100	COM
LCMxo640C-4M100C	640	1.8V/2.5V/3.3V	74	-4	csBGA	100	COM
LCMxo640C-5M100C	640	1.8V/2.5V/3.3V	74	-5	csBGA	100	COM
LCMxo640C-3T144C	640	1.8V/2.5V/3.3V	113	-3	TQFP	144	COM
LCMxo640C-4T144C	640	1.8V/2.5V/3.3V	113	-4	TQFP	144	COM
LCMxo640C-5T144C	640	1.8V/2.5V/3.3V	113	-5	TQFP	144	COM
LCMxo640C-3M132C	640	1.8V/2.5V/3.3V	101	-3	csBGA	132	COM
LCMxo640C-4M132C	640	1.8V/2.5V/3.3V	101	-4	csBGA	132	COM
LCMxo640C-5M132C	640	1.8V/2.5V/3.3V	101	-5	csBGA	132	COM
LCMxo640C-3B256C	640	1.8V/2.5V/3.3V	159	-3	caBGA	256	COM
LCMxo640C-4B256C	640	1.8V/2.5V/3.3V	159	-4	caBGA	256	COM
LCMxo640C-5B256C	640	1.8V/2.5V/3.3V	159	-5	caBGA	256	COM
LCMxo640C-3FT256C	640	1.8V/2.5V/3.3V	159	-3	ftBGA	256	COM
LCMxo640C-4FT256C	640	1.8V/2.5V/3.3V	159	-4	ftBGA	256	COM
LCMxo640C-5FT256C	640	1.8V/2.5V/3.3V	159	-5	ftBGA	256	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo1200C-3T100C	1200	1.8V/2.5V/3.3V	73	-3	TQFP	100	COM
LCMxo1200C-4T100C	1200	1.8V/2.5V/3.3V	73	-4	TQFP	100	COM
LCMxo1200C-5T100C	1200	1.8V/2.5V/3.3V	73	-5	TQFP	100	COM
LCMxo1200C-3T144C	1200	1.8V/2.5V/3.3V	113	-3	TQFP	144	COM
LCMxo1200C-4T144C	1200	1.8V/2.5V/3.3V	113	-4	TQFP	144	COM
LCMxo1200C-5T144C	1200	1.8V/2.5V/3.3V	113	-5	TQFP	144	COM
LCMxo1200C-3M132C	1200	1.8V/2.5V/3.3V	101	-3	csBGA	132	COM
LCMxo1200C-4M132C	1200	1.8V/2.5V/3.3V	101	-4	csBGA	132	COM
LCMxo1200C-5M132C	1200	1.8V/2.5V/3.3V	101	-5	csBGA	132	COM
LCMxo1200C-3B256C	1200	1.8V/2.5V/3.3V	211	-3	caBGA	256	COM
LCMxo1200C-4B256C	1200	1.8V/2.5V/3.3V	211	-4	caBGA	256	COM
LCMxo1200C-5B256C	1200	1.8V/2.5V/3.3V	211	-5	caBGA	256	COM
LCMxo1200C-3FT256C	1200	1.8V/2.5V/3.3V	211	-3	ftBGA	256	COM
LCMxo1200C-4FT256C	1200	1.8V/2.5V/3.3V	211	-4	ftBGA	256	COM
LCMxo1200C-5FT256C	1200	1.8V/2.5V/3.3V	211	-5	ftBGA	256	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo1200E-3T100C	1200	1.2V	73	-3	TQFP	100	COM
LCMxo1200E-4T100C	1200	1.2V	73	-4	TQFP	100	COM
LCMxo1200E-5T100C	1200	1.2V	73	-5	TQFP	100	COM
LCMxo1200E-3T144C	1200	1.2V	113	-3	TQFP	144	COM
LCMxo1200E-4T144C	1200	1.2V	113	-4	TQFP	144	COM
LCMxo1200E-5T144C	1200	1.2V	113	-5	TQFP	144	COM
LCMxo1200E-3M132C	1200	1.2V	101	-3	csBGA	132	COM
LCMxo1200E-4M132C	1200	1.2V	101	-4	csBGA	132	COM
LCMxo1200E-5M132C	1200	1.2V	101	-5	csBGA	132	COM
LCMxo1200E-3B256C	1200	1.2V	211	-3	caBGA	256	COM
LCMxo1200E-4B256C	1200	1.2V	211	-4	caBGA	256	COM
LCMxo1200E-5B256C	1200	1.2V	211	-5	caBGA	256	COM
LCMxo1200E-3FT256C	1200	1.2V	211	-3	ftBGA	256	COM
LCMxo1200E-4FT256C	1200	1.2V	211	-4	ftBGA	256	COM
LCMxo1200E-5FT256C	1200	1.2V	211	-5	ftBGA	256	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo2280E-3T100C	2280	1.2V	73	-3	TQFP	100	COM
LCMxo2280E-4T100C	2280	1.2V	73	-4	TQFP	100	COM
LCMxo2280E-5T100C	2280	1.2V	73	-5	TQFP	100	COM
LCMxo2280E-3T144C	2280	1.2V	113	-3	TQFP	144	COM
LCMxo2280E-4T144C	2280	1.2V	113	-4	TQFP	144	COM
LCMxo2280E-5T144C	2280	1.2V	113	-5	TQFP	144	COM
LCMxo2280E-3M132C	2280	1.2V	101	-3	csBGA	132	COM
LCMxo2280E-4M132C	2280	1.2V	101	-4	csBGA	132	COM
LCMxo2280E-5M132C	2280	1.2V	101	-5	csBGA	132	COM
LCMxo2280E-3B256C	2280	1.2V	211	-3	caBGA	256	COM
LCMxo2280E-4B256C	2280	1.2V	211	-4	caBGA	256	COM
LCMxo2280E-5B256C	2280	1.2V	211	-5	caBGA	256	COM
LCMxo2280E-3FT256C	2280	1.2V	211	-3	ftBGA	256	COM
LCMxo2280E-4FT256C	2280	1.2V	211	-4	ftBGA	256	COM
LCMxo2280E-5FT256C	2280	1.2V	211	-5	ftBGA	256	COM
LCMxo2280E-3FT324C	2280	1.2V	271	-3	ftBGA	324	COM
LCMxo2280E-4FT324C	2280	1.2V	271	-4	ftBGA	324	COM
LCMxo2280E-5FT324C	2280	1.2V	271	-5	ftBGA	324	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo2280C-3TN100C	2280	1.8V/2.5V/3.3V	73	-3	Lead-Free TQFP	100	COM
LCMxo2280C-4TN100C	2280	1.8V/2.5V/3.3V	73	-4	Lead-Free TQFP	100	COM
LCMxo2280C-5TN100C	2280	1.8V/2.5V/3.3V	73	-5	Lead-Free TQFP	100	COM
LCMxo2280C-3TN144C	2280	1.8V/2.5V/3.3V	113	-3	Lead-Free TQFP	144	COM
LCMxo2280C-4TN144C	2280	1.8V/2.5V/3.3V	113	-4	Lead-Free TQFP	144	COM
LCMxo2280C-5TN144C	2280	1.8V/2.5V/3.3V	113	-5	Lead-Free TQFP	144	COM
LCMxo2280C-3MN132C	2280	1.8V/2.5V/3.3V	101	-3	Lead-Free csBGA	132	COM
LCMxo2280C-4MN132C	2280	1.8V/2.5V/3.3V	101	-4	Lead-Free csBGA	132	COM
LCMxo2280C-5MN132C	2280	1.8V/2.5V/3.3V	101	-5	Lead-Free csBGA	132	COM
LCMxo2280C-3BN256C	2280	1.8V/2.5V/3.3V	211	-3	Lead-Free caBGA	256	COM
LCMxo2280C-4BN256C	2280	1.8V/2.5V/3.3V	211	-4	Lead-Free caBGA	256	COM
LCMxo2280C-5BN256C	2280	1.8V/2.5V/3.3V	211	-5	Lead-Free caBGA	256	COM
LCMxo2280C-3FTN256C	2280	1.8V/2.5V/3.3V	211	-3	Lead-Free ftBGA	256	COM
LCMxo2280C-4FTN256C	2280	1.8V/2.5V/3.3V	211	-4	Lead-Free ftBGA	256	COM
LCMxo2280C-5FTN256C	2280	1.8V/2.5V/3.3V	211	-5	Lead-Free ftBGA	256	COM
LCMxo2280C-3FTN324C	2280	1.8V/2.5V/3.3V	271	-3	Lead-Free ftBGA	324	COM
LCMxo2280C-4FTN324C	2280	1.8V/2.5V/3.3V	271	-4	Lead-Free ftBGA	324	COM
LCMxo2280C-5FTN324C	2280	1.8V/2.5V/3.3V	271	-5	Lead-Free ftBGA	324	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo256E-3TN100C	256	1.2V	78	-3	Lead-Free TQFP	100	COM
LCMxo256E-4TN100C	256	1.2V	78	-4	Lead-Free TQFP	100	COM
LCMxo256E-5TN100C	256	1.2V	78	-5	Lead-Free TQFP	100	COM
LCMxo256E-3MN100C	256	1.2V	78	-3	Lead-Free csBGA	100	COM
LCMxo256E-4MN100C	256	1.2V	78	-4	Lead-Free csBGA	100	COM
LCMxo256E-5MN100C	256	1.2V	78	-5	Lead-Free csBGA	100	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo640E-3TN100C	640	1.2V	74	-3	Lead-Free TQFP	100	COM
LCMxo640E-4TN100C	640	1.2V	74	-4	Lead-Free TQFP	100	COM
LCMxo640E-5TN100C	640	1.2V	74	-5	Lead-Free TQFP	100	COM
LCMxo640E-3MN100C	640	1.2V	74	-3	Lead-Free csBGA	100	COM
LCMxo640E-4MN100C	640	1.2V	74	-4	Lead-Free csBGA	100	COM
LCMxo640E-5MN100C	640	1.2V	74	-5	Lead-Free csBGA	100	COM
LCMxo640E-3TN144C	640	1.2V	113	-3	Lead-Free TQFP	144	COM
LCMxo640E-4TN144C	640	1.2V	113	-4	Lead-Free TQFP	144	COM
LCMxo640E-5TN144C	640	1.2V	113	-5	Lead-Free TQFP	144	COM
LCMxo640E-3MN132C	640	1.2V	101	-3	Lead-Free csBGA	132	COM
LCMxo640E-4MN132C	640	1.2V	101	-4	Lead-Free csBGA	132	COM
LCMxo640E-5MN132C	640	1.2V	101	-5	Lead-Free csBGA	132	COM
LCMxo640E-3BN256C	640	1.2V	159	-3	Lead-Free caBGA	256	COM
LCMxo640E-4BN256C	640	1.2V	159	-4	Lead-Free caBGA	256	COM
LCMxo640E-5BN256C	640	1.2V	159	-5	Lead-Free caBGA	256	COM
LCMxo640E-3FTN256C	640	1.2V	159	-3	Lead-Free ftBGA	256	COM
LCMxo640E-4FTN256C	640	1.2V	159	-4	Lead-Free ftBGA	256	COM
LCMxo640E-5FTN256C	640	1.2V	159	-5	Lead-Free ftBGA	256	COM

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo256E-3TN100I	256	1.2V	78	-3	Lead-Free TQFP	100	IND
LCMxo256E-4TN100I	256	1.2V	78	-4	Lead-Free TQFP	100	IND
LCMxo256E-3MN100I	256	1.2V	78	-3	Lead-Free csBGA	100	IND
LCMxo256E-4MN100I	256	1.2V	78	-4	Lead-Free csBGA	100	IND

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo640E-3TN100I	640	1.2V	74	-3	Lead-Free TQFP	100	IND
LCMxo640E-4TN100I	640	1.2V	74	-4	Lead-Free TQFP	100	IND
LCMxo640E-3MN100I	640	1.2V	74	-3	Lead-Free csBGA	100	IND
LCMxo640E-4MN100I	640	1.2V	74	-4	Lead-Free csBGA	100	IND
LCMxo640E-3TN144I	640	1.2V	113	-3	Lead-Free TQFP	144	IND
LCMxo640E-4TN144I	640	1.2V	113	-4	Lead-Free TQFP	144	IND
LCMxo640E-3MN132I	640	1.2V	101	-3	Lead-Free csBGA	132	IND
LCMxo640E-4MN132I	640	1.2V	101	-4	Lead-Free csBGA	132	IND
LCMxo640E-3BN256I	640	1.2V	159	-3	Lead-Free caBGA	256	IND
LCMxo640E-4BN256I	640	1.2V	159	-4	Lead-Free caBGA	256	IND
LCMxo640E-3FTN256I	640	1.2V	159	-3	Lead-Free ftBGA	256	IND
LCMxo640E-4FTN256I	640	1.2V	159	-4	Lead-Free ftBGA	256	IND

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo1200E-3TN100I	1200	1.2V	73	-3	Lead-Free TQFP	100	IND
LCMxo1200E-4TN100I	1200	1.2V	73	-4	Lead-Free TQFP	100	IND
LCMxo1200E-3TN144I	1200	1.2V	113	-3	Lead-Free TQFP	144	IND
LCMxo1200E-4TN144I	1200	1.2V	113	-4	Lead-Free TQFP	144	IND
LCMxo1200E-3MN132I	1200	1.2V	101	-3	Lead-Free csBGA	132	IND
LCMxo1200E-4MN132I	1200	1.2V	101	-4	Lead-Free csBGA	132	IND
LCMxo1200E-3BN256I	1200	1.2V	211	-3	Lead-Free caBGA	256	IND
LCMxo1200E-4BN256I	1200	1.2V	211	-4	Lead-Free caBGA	256	IND
LCMxo1200E-3FTN256I	1200	1.2V	211	-3	Lead-Free ftBGA	256	IND
LCMxo1200E-4FTN256I	1200	1.2V	211	-4	Lead-Free ftBGA	256	IND

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo2280E-3TN100I	2280	1.2V	73	-3	Lead-Free TQFP	100	IND
LCMxo2280E-4TN100I	2280	1.2V	73	-4	Lead-Free TQFP	100	IND
LCMxo2280E-3TN144I	2280	1.2V	113	-3	Lead-Free TQFP	144	IND
LCMxo2280E-4TN144I	2280	1.2V	113	-4	Lead-Free TQFP	144	IND
LCMxo2280E-3MN132I	2280	1.2V	101	-3	Lead-Free csBGA	132	IND
LCMxo2280E-4MN132I	2280	1.2V	101	-4	Lead-Free csBGA	132	IND
LCMxo2280E-3BN256I	2280	1.2V	211	-3	Lead-Free caBGA	256	IND
LCMxo2280E-4BN256I	2280	1.2V	211	-4	Lead-Free caBGA	256	IND
LCMxo2280E-3FTN256I	2280	1.2V	211	-3	Lead-Free ftBGA	256	IND
LCMxo2280E-4FTN256I	2280	1.2V	211	-4	Lead-Free ftBGA	256	IND
LCMxo2280E-3FTN324I	2280	1.2V	271	-3	Lead-Free ftBGA	324	IND
LCMxo2280E-4FTN324I	2280	1.2V	271	-4	Lead-Free ftBGA	324	IND